

L Number	Hits	Search Text	DB	Time stamp
1	2	5888857.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/08 10:55
2	2	5744822.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/08 10:55
3	16	(US-6346437-\$ or US-6319761-\$ or US-6162667-\$ or US-5804473-\$ or US-5252502-\$ or US-5147826-\$ or US-6084247-\$ or US-6077731-\$ or US-5275851-\$ or US-6475840-\$ or US-5932893-\$ or US-5580792-\$ or US-6413805-\$ or US-5744822-\$ or US-5624851-\$).did. or (US-20010053613-\$).did.	USPAT; US-PGPUB	2003/08/08 11:44
4	51	("4727044"   "5147826"   "5200846"   "5275851"   "5313076"   "5318661"   "5352291"   "5403772"   "5426064"   "5481121"   "5488000"   "5492843"   "5501989"   "5508533"   "5529937"   "5531182"   "5534716"   "5543352"   "5563426"   "5569610"   "5569936"   "5580792"   "5585291"   "5589694"   "5595923"   "5595944"   "5604360"   "5605846"   "5606179"   "5608232"   "5612250"   "5614426"   "5614733"   "5616506"   "5620910"   "5621224"   "5624851"   "5637515"   "5639698"   "5643826"   "5646424"   "5654203"   "5656825"   "5663077"   "5677549"   "5696386"   "5696388"   "5700333"   "5705829"   "5712191"   "5756364").PN.	USPAT	2003/08/08 11:47
-	430	(tft or thin adj film adj transistor) and (single adj grain or single adj crystal or polycrystal or single adj crystalline or polycrystalline or poly adj crystal or poly adj crystalline or polysilicon or large adj grain) with (doping or dopant or doped or implant or implanting or implantation or implanted or diffusing or diffusion or diffused) with (aluminum or al or nickel or ni or titanium or ti or cobalt or co or palladium or pd or transition adj metal)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/06 15:44
-	282	((tft or thin adj film adj transistor) and (single adj grain or single adj crystal or polycrystal or single adj crystalline or polycrystalline or poly adj crystal or poly adj crystalline or polysilicon or large adj grain) with (doping or dopant or doped or implant or implanting or implantation or implanted or diffusing or diffusion or diffused) with (aluminum or al or nickel or ni or titanium or ti or cobalt or co or palladium or pd or transition adj metal)) and (anneal or annealing or annealed)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/06 15:10
-	188	(tft or thin adj film adj transistor) and (single adj grain or single adj crystal or polycrystal or single adj crystalline or polycrystalline or poly adj crystal or poly adj crystalline or polysilicon or large adj grain) with (doping or dopant or doped or implant or implanting or implantation or implanted or diffusing or diffusion or diffused) near4 (aluminum or al or nickel or ni or titanium or ti or cobalt or co or palladium or pd or transition adj metal)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/06 15:45

137	(tft or thin adj film adj transistor) and (single adj grain or single adj crystal or polycrystal or single adj crystalline or polycrystalline or poly adj crystal or poly adj crystalline or polysilicon or large adj grain) with (doping or dopant or doped or implant or implanting or implantation or implanted or diffusing or diffusion or diffused) near4 (aluminum or al or nickel or ni or titanium or ti or cobalt or co or palladium or pd or transition adj metal) and (anneal or annealing or rta or annealed)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/06 16:04
5	("5147826"   "5275851"   "6077731"   "6084247"   "6162667").PN.	USPAT	2003/08/06 15:56
473	(tft or thin adj film adj transistor) and (single adj grain or single adj crystal or polycrystal or single adj crystalline or polycrystalline or poly adj crystal or poly adj crystalline or polysilicon or large adj grain or crystalline or crystallize or crystallized or crystallization) near5 (catalyst or catalytic or nucleation) near4 (aluminum or al or nickel or ni or titanium or ti or cobalt or co or palladium or pd or transition adj metal) and (anneal or annealing or rta or annealed)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/06 16:15
182	((tft or thin adj film adj transistor) and (single adj grain or single adj crystal or polycrystal or single adj crystalline or polycrystalline or poly adj crystal or poly adj crystalline or polysilicon or large adj grain or crystalline or crystallize or crystallized or crystallization) near5 (catalyst or catalytic or nucleation) near4 (aluminum or al or nickel or ni or titanium or ti or cobalt or co or palladium or pd or transition adj metal) and (anneal or annealing or rta or annealed)) and (single adj grain or single adj crystal or polycrystal or single adj crystalline or polycrystalline or poly adj crystal or poly adj crystalline or polysilicon or large adj grain or crystalline or crystallize or crystallized or crystallization) near4 (source or drain or channel)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/06 16:08
39	(tft or thin adj film adj transistor) and (single adj grain or single adj crystal or polycrystal or single adj crystalline or polycrystalline or poly adj crystal or poly adj crystalline or polysilicon or large adj grain or crystalline or crystallize or crystallized or crystallization) near5 (doped or doping or implanted or implanting or dope or implant or diffuse or diffusion or diffusing or diffused or implantation) near3 (catalyst or catalytic or nucleation) near4 (aluminum or al or nickel or ni or titanium or ti or cobalt or co or palladium or pd or transition adj metal) and (anneal or annealing or rta or annealed)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/06 16:16
7	6162667.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/07 10:35
14	("5147826"   "5275851"   "5481121"   "5492843"   "5501989"   "5529937"   "5534716"   "5543352"   "5550070"   "5580792"   "5585291"   "5612250"   "5643826"   "5654203").PN.	USPAT	2003/08/07 10:31

-	75	(amorphous or polycrystalline) near3 (silicon or germanium or si or ge or sige) and (implant or implanting or implanted or implantation) near2 (3d adj metal or transition adj metal or aluminum or nickel or ni or titanium or ti or cobalt or co or palladium or pd) with (crystallization or crystallize or crystallized or crystallizing or single near2 crystal or single near2 grain)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/07 12:47
-	11	("4571486"   "4772927"   "4986213"   "5147826"   "5156994"   "5236850"   "5252502"   "5275851"   "5278093"   "5328861"   "5352291").PN.	USPAT	2003/08/07 12:14
-	21	("4420870"   "4514253"   "4727044"   "4746628"   "4755865"   "4769686"   "4772927"   "4912061"   "5142344"   "5147826"   "5229625"   "5275851"   "5341012"   "5403772"   "5418389"   "5563426"   "5563440"   "5569936"   "5576556"   "5592008"   "5608232").PN.	USPAT	2003/08/07 12:44
-	20	(amorphous or polycrystalline) near3 (silicon or germanium or si or ge or sige) and (implant or implanting or implanted or implantation or doping or doped or dope or diffusing or diffusion or diffused) near2 (3d adj metal or transition adj metal or aluminum or nickel or ni or titanium or ti or cobalt or co or palladium or pd) with (crystallization or crystallize or crystallized or crystallizing or single near2 crystal or single near2 grain) and (nucleus or nucleation) near8 (radius or separation or distance or spaced or separated or separate or distanced or interval or density)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/07 14:19
-	8	(amorphous or polycrystalline) near3 (silicon or germanium or si or ge or sige) and (implant or implanting or implanted or implantation or doping or doped or dope or diffusing or diffusion or diffused) near2 (3d adj metal or transition adj metal or aluminum or nickel or ni or titanium or ti or cobalt or co or palladium or pd) with (crystallization or crystallize or crystallized or crystallizing or single near2 crystal or single near2 grain) and (nucleus or nucleation or catalyst or metal or catalytic or crystal or crystallization) near3 (site or center or origin or location) near8 (radius or separation or distance or spaced or separated or separate or distanced or interval or density)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/07 13:19
-	25	(amorphous or polycrystalline) near3 (silicon or germanium or si or ge or sige) and (nucleus or nucleation) near5 (aluminum or nickel or ni or cobalt or co or palladium or pd or titanium or ti or 3d near metal or transition near metal) near6 (radius or separation or distance or spaced or separated or separate or distanced or interval or density)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/07 14:05
-	109	257/70.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/07 14:05

-	49	(amorphous or polycrystalline) near3 (silicon or germanium or si or ge or sige) and (implant or implanting or implanted or implantation or doping or doped or dope or diffusing or diffusion or diffused) near2 (3d adj metal or transition adj metal or aluminum or nickel or ni or titanium or ti or cobalt or co or palladium or pd) with (crystallization or crystallize or crystallized or crystallizing or single near2 crystal or single near2 grain) and (grain) near3 (radius or separation or distance or spaced or separated or separate or distanced or interval or density)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/07 14:35
-	65	(amorphous or polycrystalline) near3 (silicon or germanium or si or ge or sige) and (implant or implanting or implanted or implantation or doping or doped or dope or diffusing or diffusion or diffused) near2 (3d adj metal or transition adj metal or aluminum or nickel or ni or titanium or ti or cobalt or co or palladium or pd) with (crystallization or crystallize or crystallized or crystallizing or single near2 crystal or single near2 grain) and (grain) near3 (distance or size or separation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/07 15:47
-	348	(tft or thin adj film adj transistor) and (single adj (grain or crystal)) near4 (channel or source or drain)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/07 15:48
-	16	(tft or thin adj film adj transistor) and (single adj (grain or crystal)) near4 (channel or source or drain) with (metal or aluminum or titanium or ti or nickel or ni or cobalt or co or palladium or pd)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/07 16:20
-	235	438/162.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/07 16:21
-	99	438/162.ccls. and (crystallization or crystallize or recrystallization or recrystallize or crystallized or crystallizing or recrystallized or recrystallizing or polycrystalline or amorphous) near8 (catalyst or metal or aluminum or titanium or cobalt or palladium or nickel)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/07 16:38
-	62	438/162.ccls. and (crystallization or crystallize or recrystallization or recrystallize or crystallized or crystallizing or recrystallized or recrystallizing or polycrystalline or amorphous) near8 (nickel)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/07 16:43